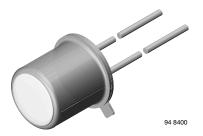
# **Vishay Semiconductors**



# Infrared Emitting Diode, RoHS Compliant, 950 nm, GaAs



## FEATURES

- Package type: leaded
- Package form: TO-18
- Dimensions (in mm): Ø 4.7
- Peak wavelength:  $\lambda_p = 950 \text{ nm}$
- High reliability
- High radiant power
- · High radiant intensity
- Angle of half intensity:  $\phi = \pm 30^{\circ}$
- · Low forward voltage
- Suitable for high pulse current operation
- · Good spectral matching with Si photodetectors
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

### **APPLICATIONS**

• Radiation source in near infrared range

### DESCRIPTION

TSTS7500 is an infrared, 950 nm emitting diode in GaAs technology in a hermetically sealed TO-18 package with flat glass window.

## **PRODUCT SUMMARY**

PRODUCT SUMM	ICDOCT SUMMART					
COMPONENT	l <sub>e</sub> (mW/sr)	φ <b>(deg)</b>	λ <sub>P</sub> (nm)	t <sub>r</sub> (ns)		
TSTS7500	1.6	± 30	950	800		

#### Note

Test conditions see table "Basic Characteristics"

## ORDERING INFORMATION

ORDERING CODE PACKAGING REMARKS PACKAGE FOR	
	1
TSTS7500 Bulk MOQ: 1000 pcs, 1000 pcs/bulk TO-18	

#### Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Reverse voltage		V <sub>R</sub>	5	V		
Forward current	T <sub>case</sub> ≤ 25 °C	١ <sub>F</sub>	250	mA		
Peak forward current	$t_p/T$ = 0.5, $t_p \leq$ 100 $\mu s,T_{case} \leq$ 25 °C	I <sub>FM</sub>	500	mA		
Surge forward current	$t_p \le 100 \ \mu s$	I <sub>FSM</sub>	2.5	А		
Power dissipation		Pv	170	mW		
Fower dissipation	T <sub>case</sub> ≤ 25 °C	Pv	500	mW		
Junction temperature		Тj	100	°C		
Storage temperature range		T <sub>stg</sub>	- 55 to + 100	°C		
Thermal resistance junction/ambient	leads not soldered	R <sub>thJA</sub>	450	K/W		
Thermal resistance junction/case	leads not soldered	R <sub>thJC</sub>	150	K/W		

#### Note

T<sub>amb</sub> = 25 °C, unless otherwise specified





Infrared Emitting Diode, RoHS Compliant, Vishay Semiconductors 950 nm, GaAs

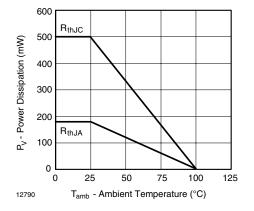


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

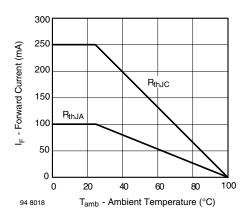


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Forward voltage	$I_F$ = 100 mA, $t_p \le$ 20 ms	V <sub>F</sub>		1.3	1.7	V		
Temperature coefficient of $V_F$	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>		- 1.3		mV/K		
Breakdown voltage	I <sub>R</sub> = 100 μA	V <sub>(BR)</sub>	5			V		
Junction capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	Cj		30		pF		
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	1.25	1.6	8	mW/sr		
Radiant power	$I_F = 100 \text{ mA}, t_p \le 20 \text{ ms}$	фе		7		mW		
Temperature coefficient of $\phi_{e}$	I <sub>F</sub> = 100 mA	ΤKφ <sub>e</sub>		- 0.8		%/K		
Angle of half intensity		φ		± 30		deg		
Peak wavelength	I <sub>F</sub> = 100 mA	λ <sub>p</sub>		950		nm		
Spectral bandwidth	I <sub>F</sub> = 100 mA	Δλ		50		nm		
Rise time	I <sub>F</sub> = 100 mA	tr		800		ns		
	$I_F = 1.5 \text{ A}, t_p/T = 0.01, t_p \le 10 \ \mu s$	t <sub>r</sub>		400		ns		
Virtual source diameter		d		0.5		mm		

#### Note

 $T_{amb} = 25$  °C, unless otherwise specified

#### **BASIC CHARACTERISTICS**

 $T_{amb}$  = 25 °C, unless otherwise specified

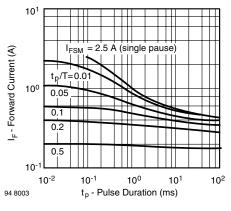


Fig. 3 - Pulse Forward Current vs. Pulse Duration

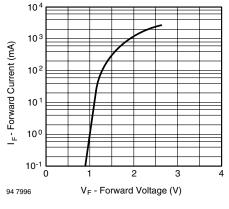


Fig. 4 - Forward Current vs. Forward Voltage

# **TSTS7500**

## Vishay Semiconductors Infrared Emitting Diode, RoHS Compliant, 950 nm, GaAs

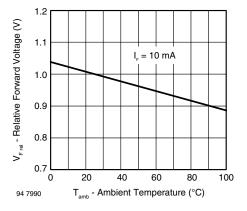


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

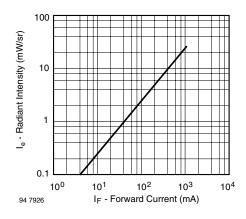


Fig. 6 - Radiant Intensity vs. Forward Current

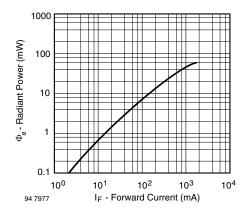


Fig. 7 - Radiant Power vs. Forward Current

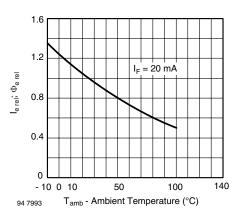


Fig. 8 - Relative Radiant Intensity/Power vs. Ambient Temperature

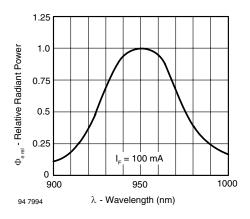


Fig. 9 - Relative Radiant Power vs. Wavelength

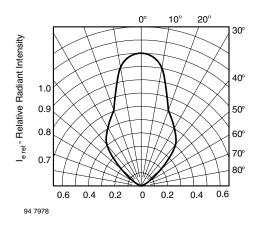


Fig. 10 - Relative Radiant Intensity vs. Angular Displacement

270

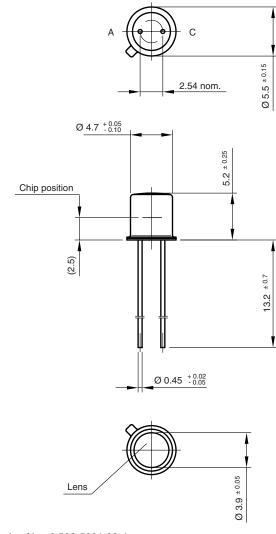
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### **PACKAGE DIMENSIONS** in millimeters





technical drawings according to DIN specifications

Drawing-No.: 6.503-5001.02-4 Issue: 1; 24.08.98 14485



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